L Number	Hits	Search Text	DB	Time stamp
66	1	("6593592").PN.	USPAT;	2003/09/22 01:45
	_	,	US-PGPUB;	
			EPO; JPO	1
67	1	(capacitor or capacitance\$2 or	USPAT;	2003/09/22 01:48
		capactive\$2) and (("6593592").PN.)	US-PGPUB;	
			EPO; JPO	
68	1	(capacitor or capacitance\$2 or	USPAT;	2003/09/22 01:53
	_	capactive\$2) same (TFT or transistor\$1 or	US-PGPUB;	
		semiconduct\$3) and (("6593592").PN.)	EPO; JPO	
69	17	(("5294869") or ("5294870") or ("5641991")	USPAT;	2003/09/22 01:53
		or ("5151629") or ("5073446") or	US-PGPUB;	
		("4769292") or ("5885211") or ("4950950")	EPO; JPO	
		or ("5882761") or ("5059861") or		
		("5839456") or ("4720432") or ("4539507")		
		or ("4356429") or ("5643826") or		
		("5923962") or ("5047687")).PN.		
70	0	(capacitor or capacitance\$2 or	USPAT;	2003/09/22 01:55
		capactive\$2) same (TFT\$1 or transistor\$1	US-PGPUB;	
		or semiconduct\$3 or FET\$1 or JFET\$1 or	EPO; JPO	
		MOSFET\$1) and ((("5294869") or ("5294870")		
		or ("5641991") or ("5151629") or		
		("5073446") or ("4769292") or ("5885211")		
		or ("4950950") or ("5882761") or		
		("5059861") or ("5839456") or ("4720432")		
		or ("4539507") or ("4356429") or		
		("5643826") or ("5923962") or		
	•	("5047687")).PN.)		1
71	0	(54)	USPAT;	2003/09/22 01:54
1		capacitance\$2 or capactive\$2) same (TFT\$1	US-PGPUB;	
		or transistor\$1 or semiconduct\$3 or FET\$1	EPO; JPO	
		or JFET\$1 or MOSFET\$1) and ((("5294869")		
		or ("5294870") or ("5641991") or		
		("5151629") or ("5073446") or ("4769292") or ("5885211") or ("4950950") or	}	
		("5882761") or ("5059861") or ("5839456")		
		or ("4720432") or ("4539507") or		
		("4356429") or ("5643826") or ("5923962")		
		or ("5047687")).PN.)	İ	
72	13399	(capacitor or capacitance\$2 or	USPAT;	2003/09/22 01:55
'-	20033	capactive\$2) same (TFT\$1 or transistor\$1	US-PGPUB;	2003, 03, 22 01.33
1		or semiconduct\$3 or FET\$1 or JFET\$1 or	EPO; JPO	
		MOSFET\$1) and impurit\$4 and gate\$1 and	,	
		(insulat\$4 or dielectric\$4)		
73	10995	(315/\$7.ccls. or 313/\$7.ccls. or	USPAT;	2003/09/22 01:57
		257/\$7.ccls. or 428/\$7.ccls. or	US-PGPUB;	
		438/\$7.ccls. or 437/\$7.ccls.) and	EPO; JPO	
1		((capacitor or capacitance\$2 or		
		capactive\$2) same (TFT\$1 or transistor\$1		
		or semiconduct\$3 or FET\$1 or JFET\$1 or		
]		MOSFET\$1) and impurit\$4 and gate\$1 and		
_		(insulat\$4 or dielectric\$4))		
74	5943	(light\$4 or EL\$1 or OLED\$1 or LED\$1 or	USPAT;	2003/09/22 01:58
		OEL\$1 or luminescen\$3) and ((315/\$7.ccls.	US-PGPUB;	
		or 313/\$7.ccls. or 257/\$7.ccls. or	EPO; JPO	
		428/\$7.ccls. or 438/\$7.ccls. or		
		437/\$7.ccls.) and ((capacitor or		
		capacitance\$2 or capactive\$2) same (TFT\$1		
		or transistor\$1 or semiconduct\$3 or FET\$1 or JFET\$1 or MOSFET\$1) and impurit\$4 and		
		gate\$1 and (insulat\$4 or dielectric\$4)))		
75	4899	channel\$1 and ((light\$4 or EL\$1 or OLED\$1	USPAT;	2003/09/22 01:58
'	4000	or LED\$1 or OEL\$1 or luminescen\$3) and	US-PGPUB;	2003/03/22 01:30
		((315/\$7.ccls. or 313/\$7.ccls. or	EPO; JPO	
		257/\$7.ccls. or 428/\$7.ccls. or		
		438/\$7.ccls. or 437/\$7.ccls.) and		
		((capacitor or capacitance\$2 or		
		capactive\$2) same (TFT\$1 or transistor\$1		
		or semiconduct\$3 or FET\$1 or JFET\$1 or		
] [MOSFET\$1) and impurit\$4 and gate\$1 and		
		(insulat\$4 or dielectric\$4))))		
				

76	700	cathode\$1 and anode\$1 and (channel\$1 and ((light\$4 or EL\$1 or OLED\$1 or LED\$1 or OEL\$1 or luminescen\$3) and ((315/\$7.ccls. or 313/\$7.ccls. or 257/\$7.ccls. or 428/\$7.ccls. or 438/\$7.ccls. or 437/\$7.ccls.) and ((capacitor or capacitance\$2 or capactive\$2) same (TFT\$1 or transistor\$1 or semiconduct\$3 or FET\$1 or JFET\$1 or MOSFET\$1) and impurit\$4 and gate\$1 and (insulat\$4 or dielectric\$4)))))	USPAT; US-PGPUB; EPO; JPO	2003/09/22 02:28
77	4899	impurit\$4 and (channel\$1 and ((light\$4 or EL\$1 or OLED\$1 or LED\$1 or OEL\$1 or luminescen\$3) and ((315/\$7.ccls. or 313/\$7.ccls. or 257/\$7.ccls. or 428/\$7.ccls. or 438/\$7.ccls. or 437/\$7.ccls.) and ((capacitor or capacitance\$2 or capactive\$2) same (TFT\$1 or transistor\$1 or semiconduct\$3 or FET\$1 or JFET\$1 or MOSFET\$1) and impurit\$4 and gate\$1 and (insulat\$4 or dielectric\$4)))))	USPAT; US-PGPUB; EPO; JPO	2003/09/22 02:28
78	1	impurit\$4 and (("6593592").PN.)	USPAT; US-PGPUB; EPO; JPO	2003/09/22 02:30
79	1	insulat\$4 and (("6593592").PN.)	USPAT; US-PGPUB; EPO; JPO	2003/09/22 02:37
80	1	gate and (("6593592").PN.)	USPAT; US-PGPUB; EPO; JPO	2003/09/22 02:37
81	1	gate near2 electrode\$1 and (("6593592").PN.)	USPAT; US-PGPUB; EPO; JPO	2003/09/22 03:44
82	1	capacitor near2 electrode\$1 and (("6593592").PN.)	USPAT; US-PGPUB; EPO; JPO	2003/09/22 02:40
83	1	light\$4 and (("6593592").PN.)	USPAT; US-PGPUB; EPO; JPO	2003/09/22 03:44
84	1	emit\$5 and (("6593592").PN.)	USPAT; US-PGPUB; EPO; JPO	2003/09/22 03:45
85	1		USPAT; US-PGPUB; EPO; JPO	2003/09/22 03:46
86	:	material and (("6593592").PN.)	USPAT; US-PGPUB; EPO; JPO	2003/09/22 03:47
87	1	dvd and (("6593592").PN.)	USPAT; US-PGPUB; EPO; JPO	2003/09/22 03:49
88		drain and (("6593592").PN.)	USPAT; US-PGPUB; EPO; JPO	2003/09/22 03:49
89	1	,,,,,,,	USPAT; US-PGPUB; EPO; JPO	2003/09/22 03:51
90			USPAT; US-PGPUB; EPO; JPO	2003/09/22 03:53
91	1		USPAT; US-PGPUB; EPO; JPO	2003/09/22 03:55
92	1	interlayer and (("6593592").PN.)	USPAT; US-PGPUB; EPO; JPO	2003/09/22 03:57
93		interlayer same electrode and (("6593592").PN.)	USPAT; US-PGPUB; EPO; JPO	2003/09/22 04:03
94	1	crystalline and (("6593592").PN.)	USPAT; US-PGPUB; EPO; JPO	2003/09/22 04:04

95	1	crystalline near5 channel and	USPAT;	2003/09/22 04:11
		(("6593592").PN.)	US-PGPUB;	
	•		EPO; JPO	
96	1	gate near5 wiring and (("6593592").PN.)	USPAT;	2003/09/22 04:28
			US-PGPUB;	
			EPO; JPO	

Search History 9/22/03 4:41:40 AM Page 3